

PM-108/PM-208/PM-308
FEATURES

- Low Offset Current 200pA Max
- Low Bias Current 2nA Max
- Low Power Consumption 18mW Max @ $\pm 15V$
- Wide Supply Range $\pm 3V$ to $\pm 20V$
- High Power-Supply Rejection Ratio 96dB Min
- Low Offset Voltage Drift 5 μ V/ $^{\circ}$ C Max
- High Common-Mode Input Range $\pm 13.5V$ Min
- High Common-Mode Rejection Ratio 96dB Min
- MIL-STD-883 Processing Models Available
- Silicon-Nitride Passivation

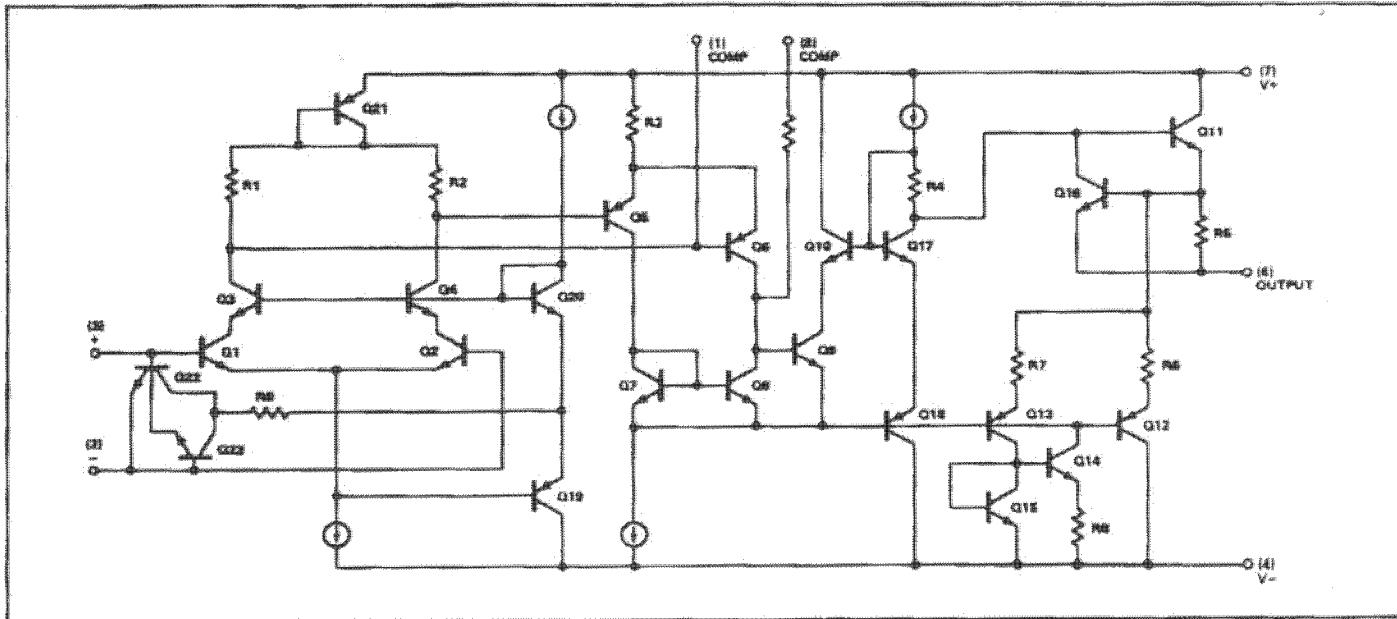
OBSOLETE

ORDERING INFORMATION

$T_A = +25^{\circ}C$	$V_{DD MAX}$ (mV)	TO-99	CERDIP 8-PIN	PACKAGE	OPERATING TEMPERATURE RANGE
0.5		PM108AJ/883	PM108AZ*	LCC 28-CONTACT	—
0.5		PM308AJ	—	—	—
2.0		PM108J/883	PM108Z*	—	—
2.0		PM208J	PM208Z	—	—
7.5		—	PM308Z	—	—

* For devices processed in total compliance to MIL-STD-883, add 883 after part number. Consult factory for 883 data sheet.

† Burn-in is available on commercial and industrial temperature range parts in CerDIP, plastic DIP, and TO-can packages.

SIMPLIFIED SCHEMATIC


PM-108/PM-208/PM-308

ABSOLUTE MAXIMUM RATINGS (Note 3)

Supply Voltage	
PM-108A, PM-108, PM-208, PM-108ARC	±20V
PM-308A, PM-308	±18V
Differential Input Current (Note 2)	±10mA
Input Voltage (Note 3)	±15V
Output Short-Circuit Duration	Indefinite
Operating Temperature Range	
PM-108A, PM-108, PM-108ARC	-55°C to +125°C
PM-208	-25°C to +85°C
PM-308A, PM-308	0°C to +70°C
Storage Temperature Range	
(Q-, J-, Z- or ARC-Package)	-65°C to +150°C
(P-Package)	-65°C to +125°C
Lead Temperature (Soldering, 60 sec)	+300°C

PACKAGE TYPE	θ_{JA} (Note 1)	θ_{JC}	UNITS
TO-99 (J)	150	18	°C/W
8-Pin Hermetic DIP (Z)	148	18	°C/W
8-Pin Plastic DIP (P)	103	43	°C/W
20-Contact LCC (RC)	98	38	°C/W

NOTES:

1. θ_{JA} is specified for worst case mounting conditions, i.e., θ_{JA} is specified for device in socket for TO, CerDIP, P-DIP, and LCC packages.
2. The inputs are shunted with back-to-back diodes for overvoltage protection; therefore, if a differential input voltage in excess of 1V is applied between the inputs, excessive current will flow, unless some limiting resistance is provided.
3. For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

ELECTRICAL CHARACTERISTICS at $\pm 5V \leq V_S \leq \pm 20V$ and $T_A = 25^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	PM-108A			PM-108 PM-208			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}		—	0.3	0.5	—	0.7	2.0	mV
Input Offset Current	I_{OS}		—	0.05	0.2	—	0.05	0.2	nA
Input Bias Current	I_B		—	0.8	2.0	—	0.8	2.0	nA
Input Resistance	R_{IN}	(Note 1)	30	70	—	30	70	—	MΩ
Large-Signal Voltage Gain	A_{VO}	$V_S = \pm 15V$, $V_{OUT} = \pm 10V$, $R_L \geq 10k\Omega$	80	200	—	50	300	—	V/mV
Supply Current	I_{SV}	$V_{OUT} = 0$, $V_S = 0$, Each Amplifier	—	0.3	0.6	—	0.3	0.6	mA

ELECTRICAL CHARACTERISTICS at $\pm 5V \leq V_S \leq \pm 20V$, $-55^\circ C \leq T_A \leq +125^\circ C$ for PM-108A, PM-108,
 $-25^\circ C \leq T_A \leq +85^\circ C$ for PM-208, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	PM-108A			PM-108 PM-208			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}		—	0.4	1.0	—	1.0	3.0	mV
Average Input Offset Voltage Drift	TCV_{OS}	(Note 2)	—	1	5	—	3	15	$\mu V/^\circ C$
Input Offset Current	I_{OS}		—	0.1	0.4	—	0.1	0.4	nA
Average Input Offset Current Drift	TCI_{OS}	(Note 2)	—	0.5	2.5	—	0.5	2.5	$pA/^\circ C$
Input Bias Current	I_B		—	1	3	—	1	3	nA
Large-Signal Voltage Gain	A_{VO}	$V_S = \pm 15V$, $V_{OUT} = \pm 10V$, $R_L \geq 10k\Omega$	40	200	—	25	200	—	V/mV
Output Voltage Swing	V_O	$V_S = \pm 15V$, $R_L = 10k\Omega$	±13	±14	—	±13	±14	—	V
Input Voltage Range	IVR	$V_S = \pm 15V$	±13.5	—	—	±13.5	—	—	V
Common-Mode Rejection Ratio	$CMRR$	$V_S = \pm 15V$, $V_{CM} = \pm 13.5V$	96	110	—	85	100	—	dB
Power-Supply Rejection Ratio	$PSRR$	$V_S = \pm 5V$ to $\pm 20V$	—	3	15	—	15	100	$\mu V/V$
Supply Current	I_{SV}	$V_{OUT} = 0$, $T_A = MAX$, Each Amplifier	—	0.15	0.4	—	0.15	0.4	mA

NOTES:

1. Guaranteed by input bias current.

2. Sample tested.

PM-108/PM-208/PM-308

ELECTRICAL CHARACTERISTICS at $\pm 5V \leq V_S \leq \pm 15V$ and $T_A = 25^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	PM-308A			PM-308			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{IO}		—	0.3	0.5	—	2.0	7.5	mV
Input Offset Current	I_{IO}		—	0.2	1.0	—	0.2	1.0	nA
Input Bias Current	I_B		—	1.5	7.0	—	1.5	7.0	nA
Input Resistance	R_{IN}	(Note 1)	10	40	—	10	40	—	MΩ
Large-Signal Voltage Gain	A_{VO}	$V_S = \pm 15V, V_{OUT} = \pm 10V,$ $R_L \geq 10k\Omega$	80	300	—	25	300	—	V/mV
Supply Current	I_{BY}	$V_{OUT} = 0, V_{OUT} = 0,$ Each Amplifier	—	0.3	0.8	—	0.3	0.8	mA

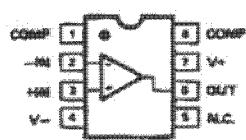
ELECTRICAL CHARACTERISTICS at $\pm 5V \leq V_S \leq \pm 15V$ and $0^\circ C \leq T_A \leq +70^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	PM-308A			PM-308			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{IO}		—	0.4	0.73	—	3.0	10.0	mV
Average Input Offset Voltage Drift	TCV_{IO}	(Note 1)	—	1	5	—	6	30	$\mu V/C$
Input Offset Current	I_{IO}		—	0.3	1.5	—	0.3	1.5	nA
Average Input Offset Current Drift	TCI_{IO}	(Note 1)	—	2	10	—	2	10	pA/C
Input Bias Current	I_B		—	2	10	—	2	10	nA
Large-Signal Voltage Gain	A_{VO}	$V_S = \pm 15V, V_{OUT} = \pm 10V,$ $R_L \geq 10k\Omega$	80	200	—	15	100	—	V/mV
Output Voltage Swing	V_O	$V_S = \pm 5V, R_L = 10k\Omega$	± 13	± 14	± 15	± 13	± 14	± 15	V
Input Voltage Range	IVR	$V_S = \pm 15V$	± 14	—	—	± 13	—	—	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 13.5V$	90	110	—	80	100	—	dB
Power-Supply Rejection Ratio	PSRR	$V_S = \pm 5V$ to $\pm 15V$	—	3	15	—	15	100	$\mu V/V$
Supply Current	I_{BY}	$V_{OUT} = 0, T_A = MAX,$ Each Amplifier	—	0.23	—	—	0.23	—	mA

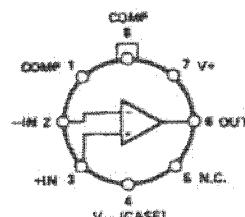
NOTE:

- Guaranteed by input bias current.

PIN CONNECTIONS

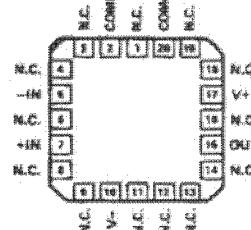


**EPOXY MINI-DIP
(P-Suffix)
AND
8-PIN HERMETIC DIP
(Z-Suffix)**



**TO-99
(J-Suffix)**

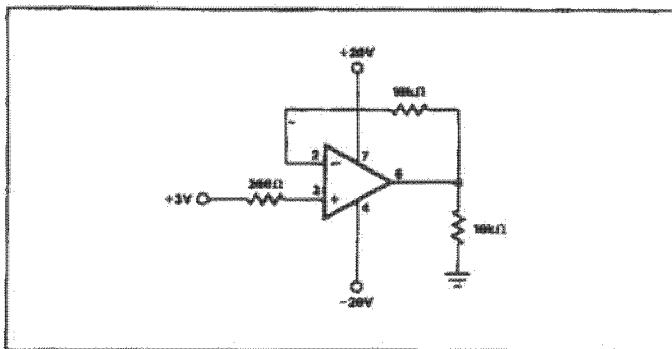
PM-108ARC/883



**LCC PACKAGE
(RC-Suffix)**

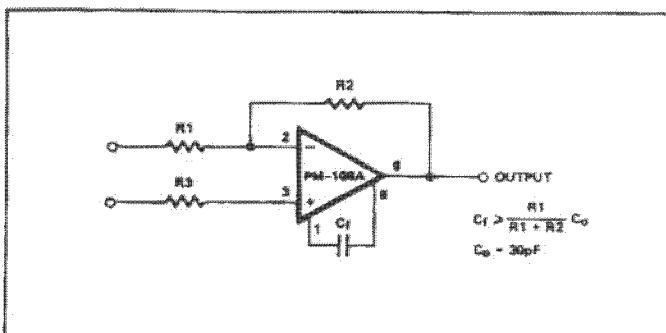
PM-108/PM-208/PM-308

BURN-IN CIRCUIT



COMPENSATION CIRCUITS

STANDARD



APPLICATIONS INFORMATION

The PM-108A series has very low input offset and bias currents; the user is cautioned that printed circuit board leakages can produce significant errors, especially at high board temperatures. Careful attention to board layout and cleaning procedure is required to achieve the PM-108A's rated performance. It is suggested that board leakage be minimized by encircling the input pins with a guard ring maintained at a potential close to that of the inputs. The guard ring should be driven by a low impedance source such as an amplifier's output or ground.

ALTERNATE

